4V Drive Pch MOS FET RSR025P03

●Structure

Silicon P-channel MOS FET

● Features

- 1) Low On-resistance
- 2) Space saving-small surface mount package (TSMT3)
- 3) 4V drive

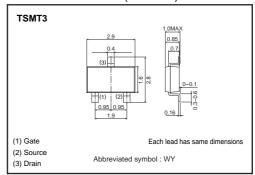
Applications

Switching

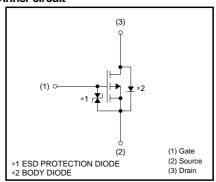
Packaging specifications

	Package	Taping	
Type	Code	TL	
	Basic ordering unit (pieces)	3000	
RSR025P03		0	

●External dimensions (Unit : mm)



•Inner circuit



● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DSS}	-30	V
Gate-source voltage		V _{GSS}	±20	V
Drain current	Continuous	I_D	±2.5	Α
	Pulsed	I _{DP} *1	±10	Α
Source current	Continuous	Is	-0.8	Α
(Body diode)	Pulsed	I _{SP} *1	-10	А
Total power dissipation		P _D *2	1	W
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	-55 to +150	°C

^{*1} Pw≤10μs, Duty cycle≤1% *2 Mounted on a ceramic board

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	125	°C/W

^{*} Mounted on a ceramic board

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	-	-	±10	μА	Vgs=±20V, Vps=0V
Drain-source breakdown voltage	$V_{(BR)\;DSS}$	-30	_	_	V	I _D = -1mA, V _G S=0V
Zero gate voltage drain current	I _{DSS}	-	_	-1	μΑ	V _{DS} = -30V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	-1.0	_	-2.5	V	$V_{DS} = -10V, I_{D} = -1mA$
Static drain-source on-state resistance		_	70	98	mΩ	I _D = -2.5A, V _G S= -10V
	R _{DS (on)} *	-	100	140	mΩ	I _D = -1.2A, V _G S= -4.5V
		-	115	160	mΩ	I _D = -1.2A, V _G S= -4V
Forward transfer admittance	Y _{fs} *	1.6	_	_	S	V _{DS} = -10V, I _D = -1.2A
Input capacitance	Ciss	-	460	_	pF	V _{DS} = -10V
Output capacitance	Coss	_	105	_	pF	Vgs=0V
Reverse transfer capacitance	Crss	_	65	_	pF	f=1MHz
Turn-on delay time	t _{d (on)} *	_	10	_	ns	V _{DD} ≒ –15V
Rise time	tr *	-	10	_	ns	I _D = -1.2A V _G s= -10V
Turn-off delay time	td (off) *	_	42	_	ns	$R_L=12.5\Omega$
Fall time	t _f *	-	10	_	ns	Rgs=10Ω
Total gate charge	Qg *	-	5.4	-	nC	V _{DD} ≒-15V V _{GS} =-5V
Gate-source charge	Q _{gs} *	-	1.4	-	nC	I _D = -2.5A
Gate-drain charge	Q _{gd} *	_	1.6	_	nC	RL=6Ω R _G =10Ω

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp	-	_	-1.2	V	I _S = -0.8A, V _{GS} =0V

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